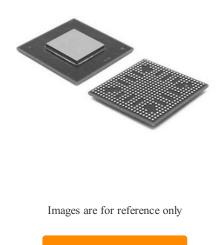


RF Amp Single LNA 10GHz 6V 6-Pin LFCSP EP T/R

Manufacturer:	Analog Devices, Inc
Package/Case:	LFCSP
Product Type:	Amplifier ICs
RoHS:	RoHS Compliant/Lead free W
Lifecycle:	Active



General Description

The HMC8410 is a gallium arsenide (GaAs), monolithic microwave integrated circuit (MMIC), pseudomorphic high electron mobility transistor (pHEMT), low noise wideband amplifier that operates from 0.01 GHz to 10 GHz. The HMC8410 provides a typical gain of 19.5 dB, a 1.1 dB typical noise figure, and a typical output IP3 of 33 dBm, requiring only 65 mA from a 5 V supply voltage. The saturated output power (PSAT) of up to 22.5 dBm enables the low noise amplifier (LNA) to function as a local oscillator (LO) driver for many of Analog Devices, Inc., balanced, I/Q or image rejection mixers. The HMC8410 also features inputs/outputs (I/Os) that are internally matched to 50 Ω , making it ideal for surface-mounted technology (SMT)-based, high capacity microwave radio applications.

The HMC8410 is housed in a RoHS-compliant, 2 mm \times 2 mm, LFCSP package. Multifunction pin names can be referenced by their relevant function only.

Key Features	Application	
Low noise figure: 1.1 dB typical	Software defined radios	
High gain: 19.5 dB typical	Electronics warfare	
High output third-order intercept (IP3): 33 dBm typical	Radar applications	
6-lead, 2 mm \times 2 mm LFCSP package		

Recommended For You

HMC624ALP4E	HMC952ALP5GE	HMC361S8GE
Analog Devices, Inc	Analog Devices, Inc	Analog Devices, Inc
QFN24	QFN	SOP-8

HMC253AQS24E

Analog Devices, Inc

QFN

HMC659LC5

Analog Devices, Inc

QFN

HMC1021LP4E

Analog Devices, Inc

QFN

HMC662LP3E

Analog Devices, Inc

QFN

HMC346MS8G

Analog Devices, Inc MSOP8

HMC909LP4E Analog Devices, Inc QFN

HMC241AQS16E

Analog Devices, Inc SSOP16

HMC8038LP4CE Analog Devices, Inc QFN16

HMC1119LP4ME

Analog Devices, Inc QFN

HMC564LC4

Analog Devices, Inc QFN

HMC424LP3E

Analog Devices, Inc QFN

HMC363S8G

Analog Devices, Inc SOP8